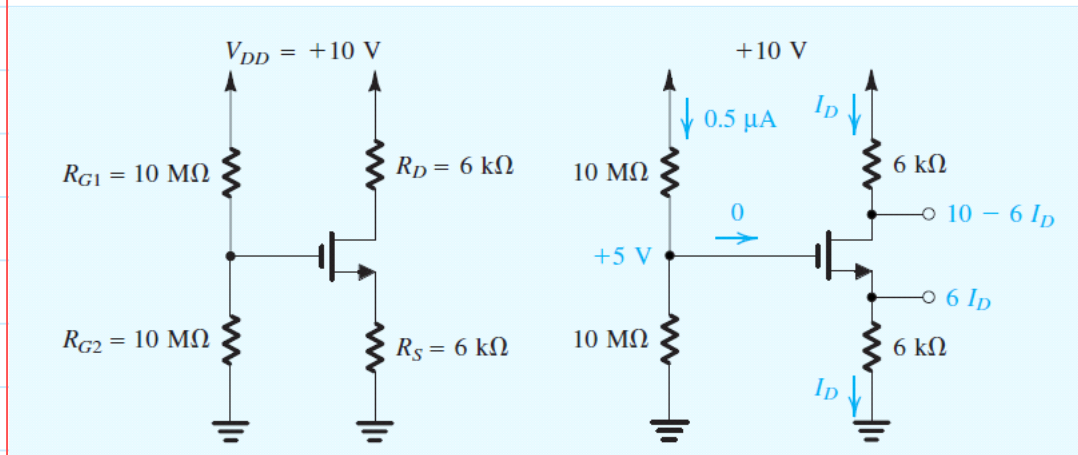


# Q1

**5.12** For the circuit of Fig. 5.24, what is the largest value that  $R_D$  can have while the transistor remains in the saturation mode?

**Ans.** 12 k $\Omega$

Let  $V_{tn} = 1$  V and  $k'_n(W/L) = 1$  mA/V<sup>2</sup>.



Hint: See the similar example, solved in the class.

In saturation  $V_{DS} > V_{OV} = V_{GS} - V_T$  &  $I_D = \frac{1}{2} k_n V_{OV}^2$

$$V_G = \frac{10}{20M} \cdot 10M = 5V \quad \text{and} \quad V_S = 0 + I_D \cdot 6k$$

$$I_D = \frac{1}{2} k_n V_{OV}^2 = \frac{1}{2} \cdot 1m \cdot (V_G - V_S - V_T)^2$$

$$= \frac{1}{2} 1m (5 - I_D \cdot 6k - 1)^2 = I_D \Rightarrow 2m = 4I_D \Rightarrow I_D = \frac{1}{2} mA$$

For saturation

$$V_S = 3V$$

$$V_{DS} > V_{OV} \Rightarrow V_{DS} > V_G - V_S - V_T = 5 - 6k \cdot \frac{1m}{2} - 1 = 1V$$

$$V_D - V_S > 1V \Rightarrow V_D - 3V > 1V \Rightarrow V_D > 4V$$

$$V_D = 10 - R_D \cdot I_D > 4 \Rightarrow 6 > R_D \cdot \frac{1m}{2} \Rightarrow \boxed{12k\Omega > R_D}$$

## Q2

**D5.9** For the circuit in Fig. E5.9, find the value of  $R$  that results in  $V_D = 0.7$  V. The MOSFET has  $V_{in} = 0.5$  V,  $\mu_n C_{ox} = 0.4$  mA/V<sup>2</sup>,  $W/L = \frac{0.72 \mu\text{m}}{0.18 \mu\text{m}}$ , and  $\lambda = 0$ .

**Ans.** 34.4 k $\Omega$

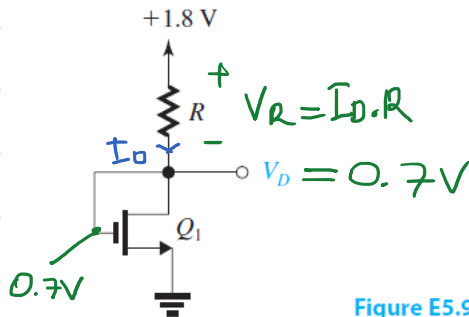


Figure E5.9

$$k_n = \mu_n C_{ox} \frac{W}{L} = 0.4 \text{ mA/V}^2 \cdot 4 = 1.6 \frac{\text{mA}}{\text{V}^2}$$

$$V_{DS} = 0.7 \text{ V} > V_{OV} = V_{GS} - V_T = 0.7 - 0.5 = 0.2$$

NMOS operates in saturation

$$I_D = \frac{1}{2} k_n V_{OV}^2 = \frac{1}{2} \cdot (1.6 \text{ mA/V}^2) \cdot (0.2)^2 = 0.032 \text{ mA} = 32 \mu\text{A}$$

$$V_D = 1.8 - I_D \cdot R \Rightarrow 0.7 = 1.8 - 32 \mu\text{A} \cdot R$$

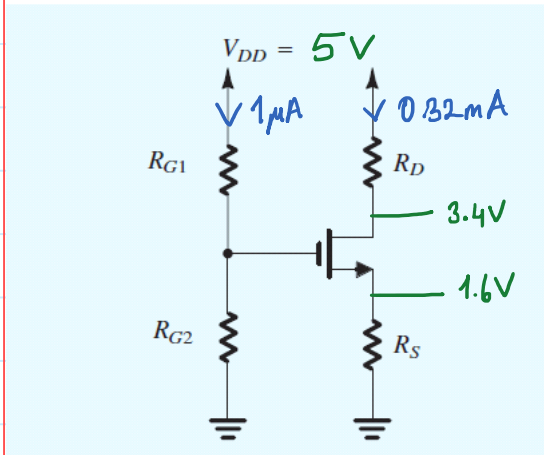
$$R = \frac{1.1}{32 \mu} \approx 34 \text{ k}\Omega$$

## Q3

**D5.13** Redesign the circuit of Fig. 5.24 for the following requirements:  $V_{DD} = +5\text{ V}$ ,  $I_D = 0.32\text{ mA}$ ,  $V_S = 1.6\text{ V}$ ,  $V_D = 3.4\text{ V}$ , with a  $1\text{-}\mu\text{A}$  current through the voltage divider  $R_{G1}$ ,  $R_{G2}$ . Assume the same MOSFET as in Example 5.6.

**Ans.**  $R_{G1} = 1.6\text{ M}\Omega$ ;  $R_{G2} = 3.4\text{ M}\Omega$ ,  $R_S = R_D = 5\text{ k}\Omega$

Let  $V_{tn} = 1\text{ V}$  and  $k'_n(W/L) = 1\text{ mA/V}^2$ .



Assume saturation  $I_D = \frac{1}{2} k'_n V_{ov}^2$  &  $V_{DS} > V_{ov} > 0$

$$0.32\text{ mA} = \frac{1}{2} \cdot 1\text{ mA} \cdot V_{ov}^2 \Rightarrow V_{ov} = \pm 0.8 \Rightarrow V_{ov} = 0.8$$

$$V_{DS} = V_D - V_S = 3.4 - 1.6 = 1.8\text{ V} > V_{ov} = 0.8\text{ V} \quad \checkmark \text{ saturation}$$

$$V_{ov} = 0.8 = V_{GS} - V_T = V_G - 1.6 - 1 \Rightarrow \boxed{V_G = 3.4\text{ V}}$$

$$R_D = \frac{5 - 3.4}{0.32\text{ mA}} = \frac{1.6}{0.32\text{ mA}} = 5\text{ k}\Omega$$

$$R_S = \frac{1.6 - 0}{0.32\text{ mA}} = \frac{1.6}{0.32\text{ mA}} = 5\text{ k}\Omega$$

$$V_G = 3.4 = \frac{5}{R_{G1} + R_{G2}} \cdot R_{G2}$$

Given that  $\frac{5}{R_{G1} + R_{G2}} = 1\text{ }\mu\text{A} \Rightarrow 3.4 = 1\text{ }\mu\text{A} \cdot R_{G2} \Rightarrow R_{G2} = 3.4\text{ M}\Omega$

$10^6 = \text{Mega}$   
↓

$$5\text{ M} = R_{G1} + R_{G2} = R_{G1} + 3.4\text{ M} \Rightarrow \boxed{R_{G1} = 1.6\text{ M}\Omega}$$